74HC4066-Q100; **74HCT4066-Q100**Quad single-pole single-throw analog switch

Rev. 3 — 16 December 2013

Product data sheet

General description

The 74HC4066-Q100; 74HCT4066-Q100 is a quad single pole, single throw analog switch. Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nE). When nE is LOW, the analog switch is turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Input levels nE inputs:
 - ◆ For 74HC4066-Q100: CMOS level
 - For 74HCT4066-Q100: TTL level
- Low ON resistance:
 - 50 Ω (typical) at $V_{CC} = 4.5 \text{ V}$
 - 45 Ω (typical) at $V_{CC} = 6.0 \text{ V}$
 - 35 Ω (typical) at $V_{CC} = 9.0 \text{ V}$
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

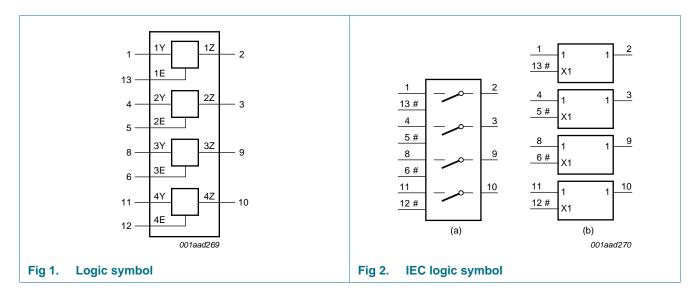


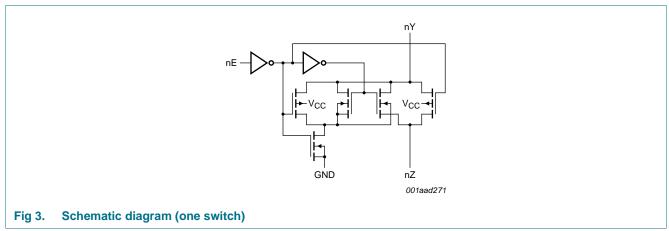
3. Ordering information

Table 1. Ordering information

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74HC4066D-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1						
74HCT4066D-Q100	Q100 3.9 mm									
74HC4066PW-Q100	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1						
74HCT4066PW-Q100			body width 4.4 mm							
74HC4066BQ-Q100	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced	SOT762-1						
74HCT4066BQ-Q100	_		very thin quad flat package; no leads; 14 terminals; body $2.5\times3\times0.85~\text{mm}$							

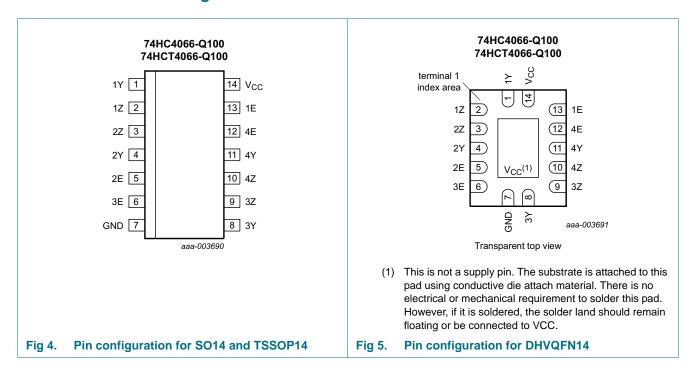
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Z, 2Z, 3Z, 4Z	2, 3, 9, 10	independent input or output
1Y, 2Y, 3Y, 4Y	1, 4, 8, 11	independent input or output
GND	7	ground (0 V)
1E, 2E, 3E, 4E	13, 5, 6, 12	enable input (active HIGH)
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table[1]

Input nE	Switch
L	OFF
Н	ON

^[1] H = HIGH voltage level;L = LOW voltage level.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+11.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	$V_{SW} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±25	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]	-	500
Р	power dissipation	per switch	-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn. In this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or GND.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74HC4066-Q100			74HCT4066-Q100			Unit
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	V
VI	input voltage		GND	-	V_{CC}	GND	-	V_{CC}	V
V_{SW}	switch voltage		GND	-	V_{CC}	GND	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	and fall rate	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
		$V_{CC} = 10.0 \text{ V}$	-	-	35	-	-	-	ns/V

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^[2] For SO14 packages: P_{tot} derates linearly with 8 mW/K above 70 °C. For TSSOP14 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C. For DHVQFN14 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

9. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4066-Q100 and 74HCT4066-Q100

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see <u>Figure 6</u>.

 V_{is} is the input voltage at a Yn or \overline{Z} terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4066-Q100: V_{CC} – GND = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4066-Q100: V_{CC} – GND = 4.5 V.

Symbol	Parameter	Conditions		–40	°C to +85	5 °C		to +125 C	Unit
				Min	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to GND							
		V_{CC} = 2.0 V; I_{SW} = 100 μA	[2]	-	-	-	-	-	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 μA		-	54	-	118	142	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 μA		-	42	-	105	126	Ω
		V_{CC} = 9.0 V; I_{SW} = 1000 μA		-	32	-	88	Max - 142	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = GND$							
		V_{CC} = 2.0 V; I_{SW} = 100 μ A	[2]	-	80	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	35	-	95	115	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 μA		-	27	-	82	100	Ω
		$V_{CC} = 9.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	20	-	70	85	Ω
		$V_{is} = V_{CC}$							
		V_{CC} = 2.0 V; I_{SW} = 100 μ A	[2]	-	100	-	-	-	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 μA		-	42	-	106	128	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	35	-	94	113	Ω
		$V_{CC} = 9.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	20	-	78	95	Ω
ΔR_{ON}	ON resistance	$V_{is} = V_{CC}$ to GND							
	mismatch between	$V_{CC} = 2.0 \text{ V}$	[2]	-	-	-		-	Ω
	channels	V _{CC} = 4.5 V		-	5	-	-	-	Ω
		$V_{CC} = 6.0 \text{ V}$		-	4	-	-	-	Ω
		V _{CC} = 9.0 V		-	3	-	-	-	Ω

^[1] Typical values are measured at $T_{amb} = 25$ °C.

^[2] At supply voltages (V_{CC} – GND) approaching 2 V, the analog switch ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

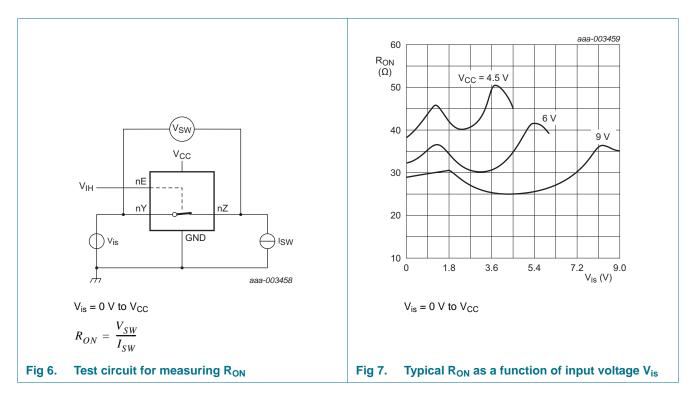


Table 7. Static characteristics 74HC4066-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$T_{amb} = -40$	0 °C to +85 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	0.8	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.80	V
		V _{CC} = 9.0 V	-	4.3	2.70	V
I _I	input leakage current	$V_I = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	.4 - V .2 - V .7 - V .8 0.5 V .1 1.35 V .8 1.80 V .3 2.70 V	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Figure 8				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} – GND; see Figure 9	-	-	±1.0	μА

Table 7. Static characteristics 74HC4066-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	20.0	μΑ
		V _{CC} = 10.0 V	-	-	40.0	μΑ
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance		-	8	-	pF
$T_{amb} = -40$	0 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.50	V
<u>.</u>		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	40.0 μ - p - V - V - V 0.50 V 1.35 V 1.80 V 2.70 V ±1.0 μ ±1.0 μ ±1.0 μ 40 μ	V
		V _{CC} = 9.0 V	-	-	2.70	V
I _I	input leakage current	$V_I = V_{CC}$ or GND			- pF - V - V - V 0.50 V 1.35 V 1.80 V 2.70 V ±1.0 μA ±2.0 μA	
		V _{CC} = 6.0 V	-	-	±1.0	μА
		V _{CC} = 10.0 V	-	-	±2.0	μА
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} = V_{CC} - GND$; see Figure 8				
		per channel	-	-	±1.0	μА
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Model}}$	-	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	40	μΑ
		V _{CC} = 10.0 V	-	-	80	μА

^[1] Typical values are measured at T_{amb} = 25 °C.

Table 8. Static characteristics 74HCT4066-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

	· ·	-				
Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$T_{amb} = -40$	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ

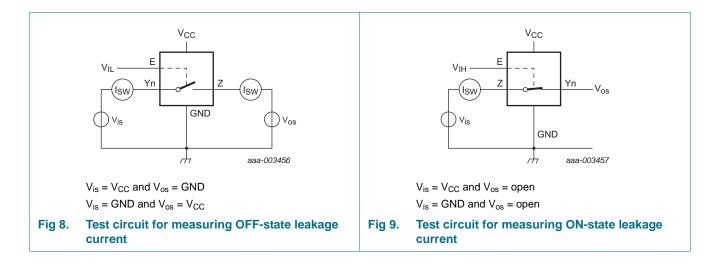
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Table 8. Static characteristics 74HCT4066-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Model}}$				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Model}}$	-	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	20.0	μА
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $V_{CC} = 4.5$ V to 5.5 V	-	100	450	μА
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance		-	8	-	pF
T _{amb} = -40	°C to +125 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		per channel	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Figure 9}}{\text{Model}}$	-	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	40	μА
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	490	μА

[1] Typical values are measured at T_{amb} = 25 °C.



10. Dynamic characteristics

Table 9. Dynamic characteristics 74HC4066-Q100

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see <u>Figure 12</u>.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		-40	°C to +85	°C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; see Figure 10	[2]					'	'
		$V_{CC} = 2.0 \text{ V}$		-	8	75	-	90	ns
		$V_{CC} = 4.5 \text{ V}$		-	3	15	-	18	ns
		$V_{CC} = 6.0 \text{ V}$		-	2	13	-	15	ns
		$V_{CC} = 9.0 \text{ V}$		-	2	10	-	12	ns
t _{off}	turn-off time	nE to nY or nZ; see Figure 11	[4]						
		$V_{CC} = 2.0 \text{ V}$		-	44	190	-	225	ns
		$V_{CC} = 4.5 \text{ V}$		-	16	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	13	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	13	33	-	38	ns
		$V_{CC} = 9.0 \text{ V}$		-	16	26	-	30	ns
t _{on}	turn-on time	nE to nY or nZ; see Figure 11	[3]						
		$V_{CC} = 2.0 \text{ V}$		-	36	125	-	150	ns
		$V_{CC} = 4.5 \text{ V}$		-	13	25	-	30	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	11	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	10	21	-	26	ns
		$V_{CC} = 9.0 \text{ V}$		-	8	16	-	20	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC}	<u>[5]</u>	11		-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 $^{\circ}C.$

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$$
 where:

f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

 C_L = output load capacitance in pF;

 C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

^[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

^[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

^[4] t_{off} is the same as t_{PZH} and t_{PZL} .

^[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

Table 10. Dynamic characteristics 74HCT4066-Q100

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see <u>Figure 12</u>.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		-40	°C to +85	S °C	-40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
t _{pd} propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; see Figure 10	[2]							
		V _{CC} = 4.5 V		-	3	15	-	18	ns
t _{off}	turn-off time	nE to nY or nZ; see Figure 11	[4]						
		V _{CC} = 4.5 V		-	20	44	-	53	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	16	-	-	-	ns
t _{on}	turn-on time	nE to nY or nZ; see Figure 11	[3]						
		V _{CC} = 4.5 V		-	12	30	-	36	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	12	-	-	-	ns
C_{PD}	power dissipation capacitance	per switch; V _I = GND to (V _{CC} – 1.5 V)	<u>[5]</u>	-	12	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} \text{ where: }$$

f_i = input frequency in MHz;

fo = output frequency in MHz;

 $\Sigma \{ (C_L + C_{sw}) \times V_{CC}^2 \times f_0 \} = \text{sum of outputs};$

C_L = output load capacitance in pF;

 C_{sw} = switch capacitance in pF;

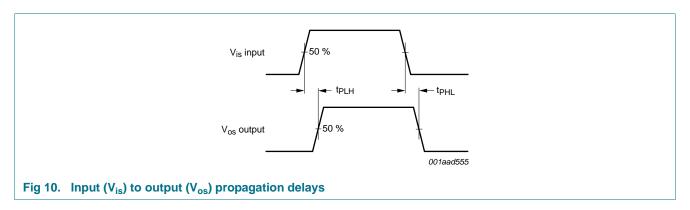
 V_{CC} = supply voltage in V.

^[2] t_{pd} is the same as t_{PHL} and t_{PLH}.

^[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

^[4] t_{off} is the same as t_{PZH} and t_{PZL} .

11. Waveforms



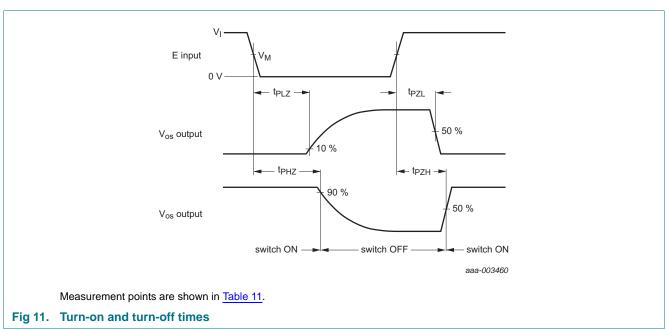
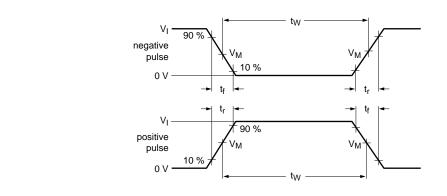
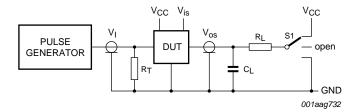


Table 11. Measurement points

Туре	V _I	V _M
74HC4066-Q100	V _{CC}	0.5V _{CC}
74HCT4066-Q100	3.0 V	1.3 V





Test data is given in Table 12.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistor.

S1 = Test selection switch.

Fig 12. Load circuitry for measuring switching times

Table 12. Test data

Test	Input			Output	Output		
	Control E	Control E Switch Yn (Z)		Switch Z (Yn)	Switch Z (Yn)		
	V _I [1]	V _{is}		C _L	R _L		
t _{PHL} , t _{PLH}	GND	GND to V _{CC}	6 ns	50 pF	-	open	
t _{PHZ} , t _{PZH}	GND to V_{CC}	V _{CC}	6 ns	50 pF, 15 pF	1 kΩ	GND	
t _{PLZ} , t _{PZL}	GND to V _{CC}	GND	6 ns	50 pF, 15 pF	1 kΩ	V _{CC}	

[1] For 74HCT4066-Q100: maximum input voltage $V_1 = 3.0 \text{ V}$.

12. Additional dynamic characteristics

Table 13. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; T_{amb} = 25 °C.

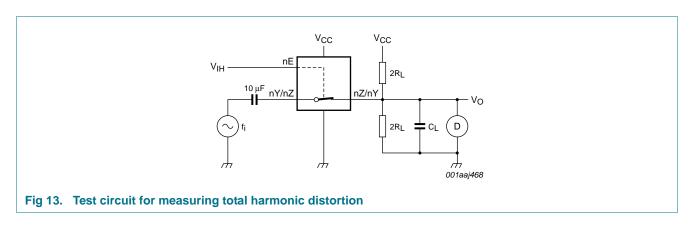
 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	$f_i = 1 \text{ kHz}; R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pF};$		٠,٢٣	max	%
		see Figure 13				, ,
	$V_{CC} = 4.5 \text{ V}; V_I = 4.0 \text{ V (p-p)}$	-	0.04	-	%	
		$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.02	-	%
		f_i = 10 kHz; R_L = 10 k Ω ; C_L = 50 pF; see Figure 13				
		$V_{CC} = 4.5 \text{ V}; V_I = 4.0 \text{ V (p-p)}$	-	0.12	-	%
		$V_{CC} = 9.0 \text{ V}; V_{I} = 8.0 \text{ V (p-p)}$	-	0.06	-	%
f _(-3dB) -3 dB frequency response	-3 dB frequency response	$R_L = 50 \Omega$; $C_L = 10 pF$; see Figure 15	[2]			
		$V_{CC} = 4.5 \text{ V}$	-	180	-	MHz
	$V_{CC} = 9.0 \text{ V}$	-	200	-	MHz	
α_{iso} isolation (OFF-state)		R_L = 600 Ω ; C_L = 50 pF; f_i = 1 MHz; see <u>Figure 14</u>	<u>[1]</u>			
		$V_{CC} = 4.5 \text{ V}$	-	-50	-	dB
		$V_{CC} = 9.0 \text{ V}$	-	-50	-	dB
V _{ct} crosstalk voltage		between digital input and switch (peak to peak value); R_L = 600 Ω ; C_L = 50 pF; f_i = 1 MHz; see Figure 16				
		V _{CC} = 4.5 V	-	110	-	mV
		V _{CC} = 9.0 V	-	220	-	mV
Xtalk	crosstalk	between switches; R _L = 600 Ω ; C _L = 50 pF; f_i = 1 MHz; see Figure 17	[1]			
		V _{CC} = 4.5 V	-	-60	-	dB
		$V_{CC} = 9.0 \text{ V}$	-	-60	-	dB

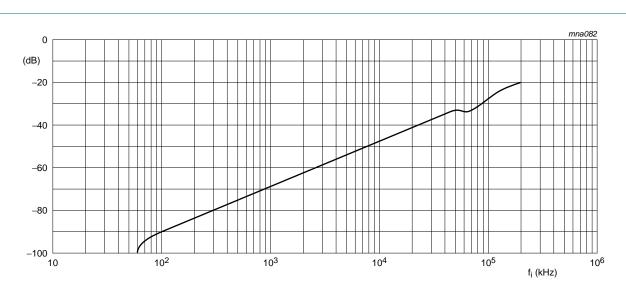
^[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

^[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for f_i = 1 MHz (0 dBm = 1 mW into 50 Ω). After set-up, f_i is increased to obtain a reading of -3 dB at V_{os}.

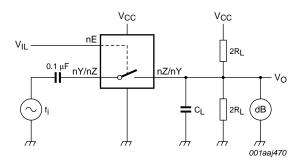


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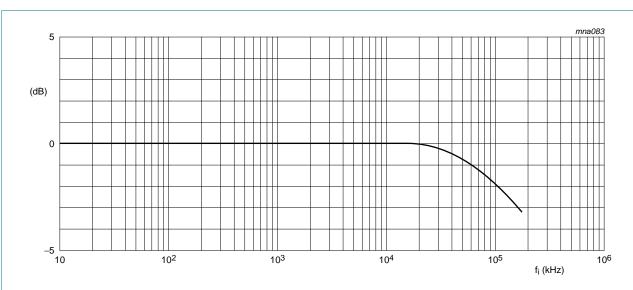
a. Isolation (OFF-state)



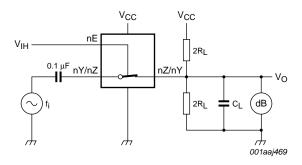
b. Test circuit

 $\mbox{V}_{\mbox{CC}}$ = 4.5 V; GND = 0 V; $\mbox{R}_{\mbox{L}}$ = 600 $\Omega;$ $\mbox{R}_{\mbox{source}}$ = 1 $\mbox{k}\Omega.$

Fig 14. Isolation (OFF-state) as a function of frequency



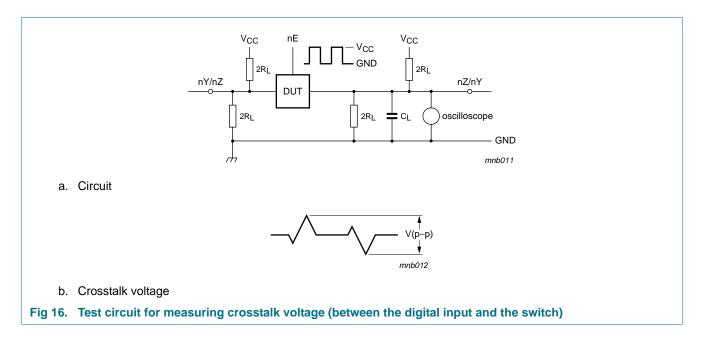
a. Typical -3 dB frequency response

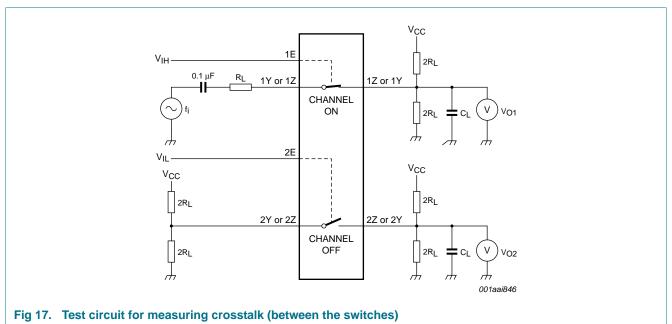


b. Test circuit

 $\mbox{V}_{\mbox{CC}}$ = 4.5 V; GND = 0 V; $\mbox{R}_{\mbox{L}}$ = 50 $\Omega;$ $\mbox{R}_{\mbox{source}}$ = 1 $\mbox{k}\Omega.$

Fig 15. -3 dB frequency response

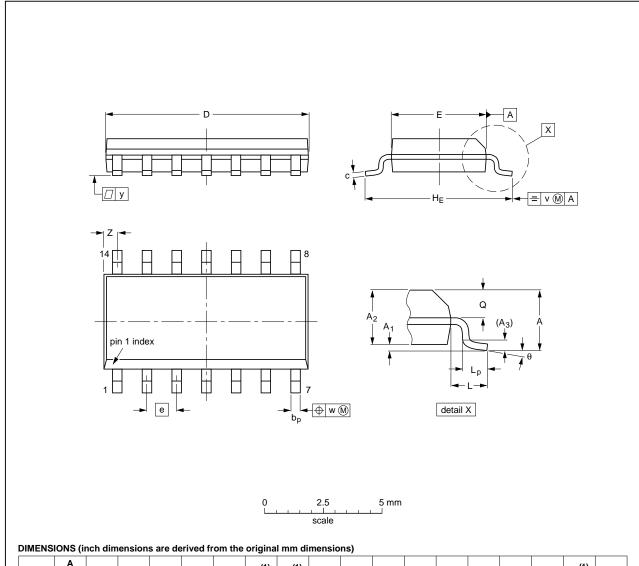




13. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	1	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012			99-12-27 03-02-19

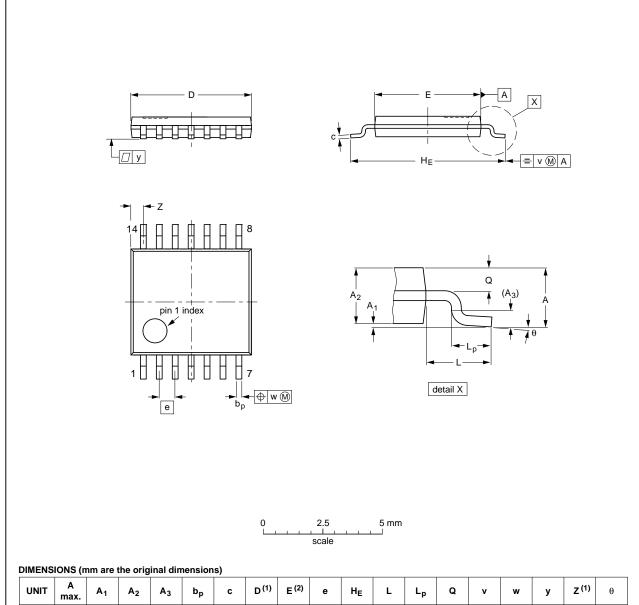
Fig 18. Package outline SOT108-1 (SO14)

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



						٠,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION	DATE	ISSUE DAT	EUROPEAN	RENCES	REFER		OUTLINE			
SOT402.1 MO.153	DATE	ISSUE DAT	PROJECTION	JEITA	JEDEC	IEC	VERSION			
03-1		99-12-27 03-02-18			MO-153		SOT402-1			

Fig 19. Package outline SOT402-1 (TSSOP14)

74HC_HCT4066_Q100

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

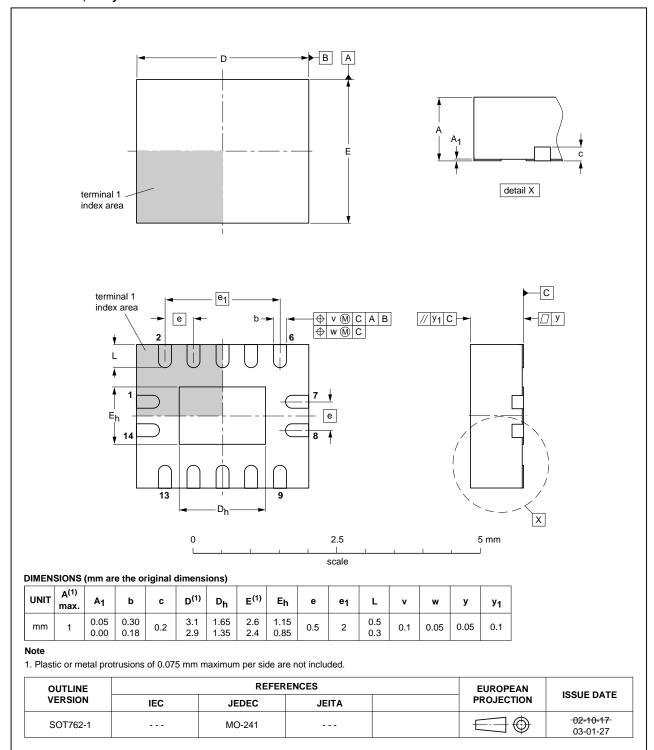


Fig 20. Package outline SOT762-1 (DHVQFN14)

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14. Abbreviations

Table 14. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
CDM	Charge-Device Model
MIL	Military

15. Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4066_Q100 v.3	20131216	Product data sheet	-	74HC_HCT4066_Q100 v.2
Modifications:	 Features and 	d benefits updated (errata).		
74HC_HCT4066_Q100 v.2	20130404	Product data sheet	-	74HC_HCT4066_Q100 v.1
Modifications:	 Descriptive ti 	tle corrected (errata).		
	 New general 	description (errata).		
74HC_HCT4066_Q100 v.1	20120712	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Quad single-pole single-throw analog switch

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Quad single-pole single-throw analog switch

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